

17213

14115

3 Hours / 100 Marks

Seat No.

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- Instructions –*
- (1) All Questions are *Compulsory*.
 - (2) Illustrate your answers with neat sketches wherever necessary.
 - (3) Figures to the right indicate full marks.
 - (4) Assume suitable data, if necessary.
 - (5) Mobile Phone, Pager and any other Electronic Communication devices are not permissible in Examination Hall.
 - (6) Preferably, write the answers in sequential order.

	Marks
1. Attempt any <u>TEN</u> of the following:	20
a) Define active and passive components. b) Draw the symbol of N-channel and P-channel JFET. c) Give the two applications of light emitting diode. d) Define current gain and voltage gain of common emitter amplifier. e) List the four specifications of PN junction diode. f) Give four advantages of IC's. g) Draw the circuit diagram of CLC filter. h) Define transconductance (gm) and amplification factor (μ) for a JFET. i) Draw the symbol of zener diode and tunnel diode. j) Give the four applications of analog IC's. k) Draw the symbol of NPN and PNP transistor. l) Draw the symbol of variable resistor and electrolytic capacitor.	

P.T.O.

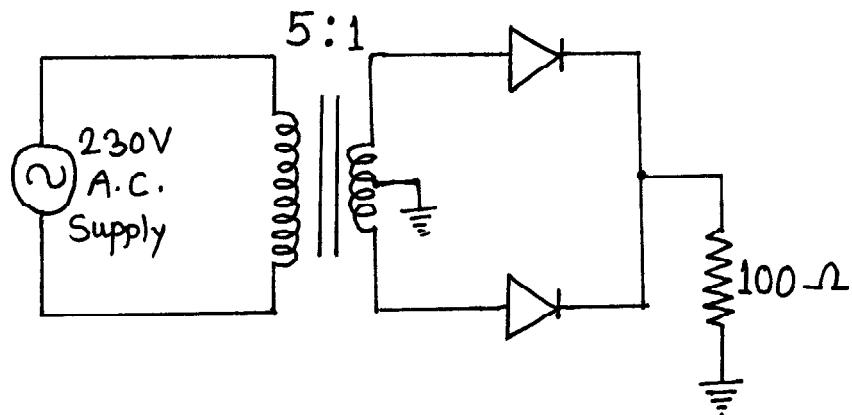
- 2. Attempt any FOUR of the following:** **16**
- a) Give the four applications of electronics in medical field.
 - b) Explain the working principle of varactor diode.
 - c) Explain the working of PNP transistor with the help of constructional diagram.
 - d) Explain the working of single stage CE amplifier with the help of circuit diagram.
 - e) Draw the experimental set-up for obtaining the reverse characteristics of a zener diode and draw its V-I characteristics for the same.
 - f) A crystal oscillator has $L = 0.33 \text{ H}$, $C = 0.065 \text{ PF}$. Find the series resonant frequency.
- 3. Attempt any FOUR of the following:** **16**
- a) Compare VDR and LDR on the basis of working principle and characteristics.
 - b) Explain the operating principle and characteristics of LED.
 - c) Draw the construction of P-channel JFET and explain the formation of depletion layer.
 - d) Compare CE and CB configuration on the basis of:
 - (i) input impedance
 - (ii) output impedance
 - (iii) current gain and
 - (iv) voltage gain.
 - e) A transistor has $IB = 105 \mu\text{A}$ and $IC = 2.05 \text{ mA}$. Find β and α of the transistor.
 - f) Draw the circuit diagram of crystal oscillator and write the expression for frequency of oscillation.

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| 4. Attempt any <u>FOUR</u> of the following: | 16 |
| a) Give four applications of Schottky diode. | |
| b) State the need of rectification. | |
| c) State advantages of FET over BJT (any four). | |
| d) Draw and explain the working of choke input (OR LC) filter. | |
| e) Draw the frequency response curve of a single stage RC coupled amplifier. Explain its behaviour at low frequencies and high frequencies (i.e. below 50 Hz and above 20 KHz respectively). | |
| f) Draw the circuit diagram of transformer coupled amplifier and its frequency response. | |
| 5. Attempt any <u>FOUR</u> of the following: | 16 |
| a) Explain the operating principle of P-N junction diode under forward bias condition. | |
| b) State the four advantages of centre-tapped full wave rectifier over half wave rectifier. | |
| c) Draw the experimental setup to plot input and output characteristics of CE configuration and label them. | |
| d) Draw the circuit diagram of bistable multivibrator using transistor and explain its working. | |
| e) List two advantages and two disadvantages of direct coupled amplifier over RC coupled amplifier. | |
| f) Draw and describe zener diode voltage regulator. | |

6. Attempt any FOUR of the following:

16

- a) Define the following terms with respect to PN junction diode:
 (i) static resistance
 (ii) dynamic resistance.
- b) What is a voltage regulator? State the necessity of voltage regulator.
- c) State the need of biasing for transistor. Draw the circuit diagram of voltage divider biasing.
- d) Write two applications of astable multivibrator and two applications of bistable multivibrator.
- e) Draw the drain characteristics of JFET and show the different regions on it.
- f) Following figure shows a centre tapped full wave rectifier circuit.

**Fig. No. 1**

Assuming both the diodes to be ideal, determine:

- (i) d.c. output voltage (V_{dc}) and
- (ii) peak inverse voltage (PIV) of diode.